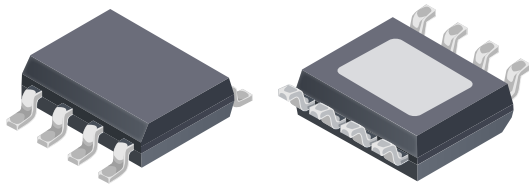


Constant-Current 3-Ampere PWM Dimmable Buck Regulator LED Driver

Features and Benefits

- Supply voltage 6 to 48 V
- True average output current control
- 3.0 A maximum output over operating temperature range
- Cycle-by-cycle current limit
- Integrated MOSFET switch
- Dimming via direct logic input or power supply voltage
- Internal control loop compensation
- Undervoltage lockout (UVLO) and thermal shutdown protection
- Low power shutdown (1 μ A typical)
- Robust protection against:
 - Adjacent pin-to-pin short
 - Pin-to-GND short
 - Component open/short faults

Package 8-pin SOICN with exposed thermal pad (suffix LJ):



Not to scale

Description

The A6211 is a single IC switching regulator that provides constant-current output to drive high-power LEDs. It integrates a high-side N-channel DMOS switch for DC-to-DC step-down (buck) conversion. A true average current is output using a cycle-by-cycle, controlled on-time method.

Output current is user-selectable by an external current sense resistor. Output voltage is automatically adjusted to drive various numbers of LEDs in a single string. This ensures the optimal system efficiency.

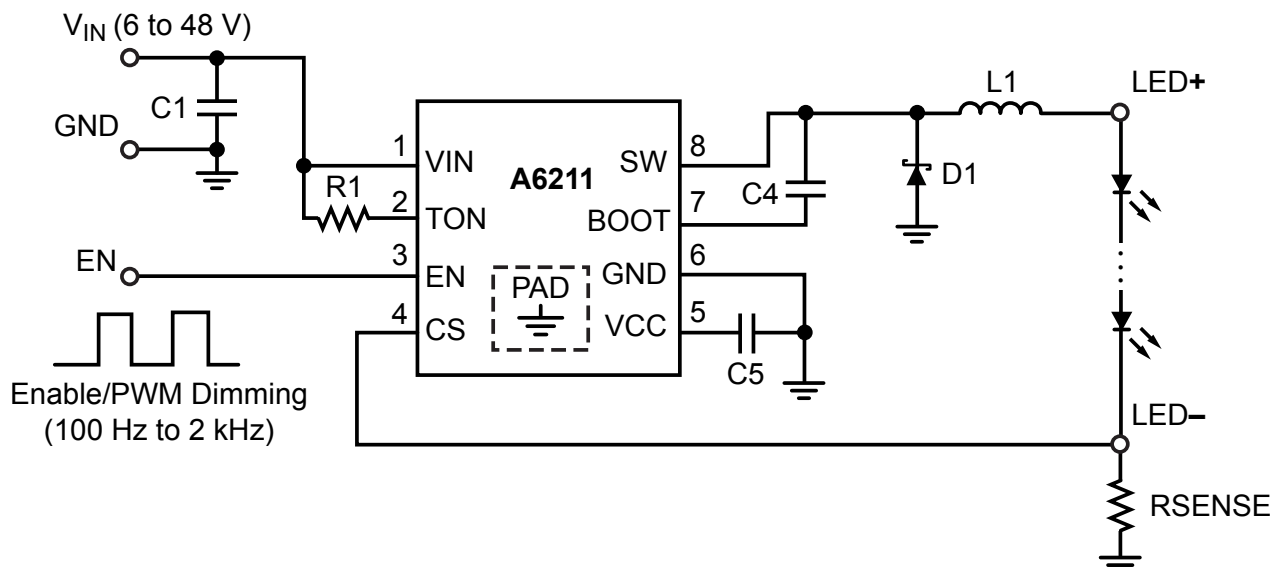
LED dimming is accomplished by a direct logic input pulse width modulation (PWM) signal at the enable pin.

The device is provided in a compact 8-pin narrow SOIC package (suffix LJ) with exposed pad for enhanced thermal dissipation. It is lead (Pb) free, with 100% matte tin leadframe plating.

Applications:

- General Illumination
- Scanners and multi-function printers (light bars)
- Architectural lighting
- Industrial Lighting
- Display case lighting / MR16

Typical Application Circuit



Selection Guide

| Part Number | Operating Ambient Temperature, T_A | Package | Packing |
|--------------|--------------------------------------|--------------------------------------|----------------------------|
| A6211GLJTR-T | -40°C to 105°C | 8-pin SOICN with exposed thermal pad | 3000 pieces per 13-in reel |

Absolute Maximum Ratings

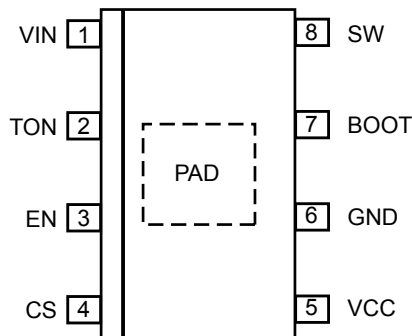
| Characteristic | Symbol | Notes | Rating | Unit |
|-------------------------------|-------------------|---------------------|------------------------|------|
| Supply Voltage | V_{IN} | | -0.3 to 50 | V |
| Bootstrap Drive Voltage | V_{BOOT} | | -0.3 to $V_{IN} + 8$ | V |
| Switching Voltage | V_{SW} | | -1.5 to $V_{IN} + 0.3$ | V |
| Linear Regulator Terminal | V_{CC} | VCC to GND | -0.3 to 14 | V |
| Enable and TON Voltage | V_{EN}, V_{TON} | | -0.3 to $V_{IN} + 0.3$ | V |
| Current Sense Voltage | V_{CS} | | -0.3 to 7 | V |
| Operating Ambient Temperature | T_A | G temperature range | -40 to 105 | °C |
| Maximum Junction Temperature | $T_J(max)$ | | 150 | °C |
| Storage Temperature | T_{stg} | | -55 to 150 | °C |

Thermal Characteristics* may require derating at maximum conditions, see application section for optimization

| Characteristic | Symbol | Test Conditions* | Value | Unit |
|--|-----------------|--|-------|------|
| Package Thermal Resistance (Junction to Ambient) | $R_{\theta JA}$ | On 4-layer PCB based on JEDEC standard | 35 | °C/W |
| | | On 2-layer generic test PCB with 0.8 in. ² of copper area each side | 62 | °C/W |
| Package Thermal Resistance (Junction to Pad) | $R_{\theta JP}$ | | 2 | °C/W |

*Additional thermal information available on the Allegro® website.

Pin-out Diagram



Terminal List Table

| Number | Name | Function |
|--------|------|--|
| 1 | VIN | Supply voltage input terminals |
| 2 | TON | Regulator on-time setting resistor terminal |
| 3 | EN | Logic input for Enable and PWM dimming |
| 4 | CS | Drive output current sense feedback |
| 5 | VCC | Internal linear regulator output |
| 6 | GND | Ground terminal |
| 7 | BOOT | DMOS gate driver bootstrap terminal |
| 8 | SW | Switched output terminals |
| — | PAD | Exposed pad for enhanced thermal dissipation; connect to GND |

The block diagram illustrates the internal architecture of the LED driver IC and its connection to external components. The IC is enclosed in a dashed box and includes the following internal blocks:

- IC and Driver Control Logic:** The central control unit that coordinates the driver's operation.
- On-Time Current Generator:** Receives the V_{IN} signal and provides a reference current to the On-Time Timer.
- On-Time Timer:** Controls the switching frequency based on the current generator and feedback signals.
- Off-Time Timer:** Controls the off-time of the switching cycle.
- Gate Drive UVLO:** Monitors the V_{CC} UVLO pin to ensure the gate driver has sufficient supply voltage.
- Level Shift:** Translates the control logic signals to the appropriate voltage levels for the MOSFET gate.
- Current Limit Off-Time Timer:** Provides a delay after a current limit event before the driver resumes operation.
- Thermal Shutdown:** Monitors the junction temperature and shuts down the driver if it exceeds a safe threshold.
- Buck Switch Current Sense:** Monitors the current through the MOSFET to implement current limiting.
- Shutdown:** A control signal that can disable the driver for power saving.
- Average:** A block that provides feedback based on the average output current.

External Components and Connections:

- Inputs:** V_{IN} (input voltage), EN (enable signal), V_{CC} (gate driver supply), and V_{CC} UVLO (gate driver UVLO pin).
- Outputs:** V_{REG} 5.3 V (regulated output), $BOOT$ (bootstrap node), SW (switch node), and CS (current sense output).
- Passive Components:** R_{ON} (input resistor), C_{COMP} (compensation capacitor), C_{BOOT} (bootstrap capacitor), $L1$ (inductor), $D1$ (diode), and R_{SENSE} (sense resistor).
- LED String:** The load connected to the output of the driver.

ELECTRICAL CHARACTERISTICS Valid at $V_{IN} = 24$ V, for $T_A = -40^{\circ}\text{C}$ to 105°C , typical values at $T_A = 25^{\circ}\text{C}$; unless otherwise noted

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|--|-----------------|--|-------|------|------|--------------------|
| Input Supply Voltage | V_{IN} | $T_A = 25^{\circ}\text{C}$ | 6 | – | 48 | V |
| V_{IN} Undervoltage Lockout Threshold | V_{UVLO} | V_{IN} increasing | – | 5.3 | – | V |
| V_{IN} Undervoltage Lockout Hysteresis | V_{UVLO_HYS} | V_{IN} decreasing | – | 150 | – | mV |
| VIN Pin Supply Current | I_{IN} | $V_{CS} = 0.5$ V, EN = high | – | 5 | – | mA |
| VIN Pin Shutdown Current | I_{INSD} | EN shorted to GND | – | 1 | 10 | μA |
| Buck Switch Current Limit Threshold | I_{SWLIM} | | 3.0 | 4.0 | 5.0 | A |
| Buck Switch On-Resistance | $R_{DS(on)}$ | $V_{BOOT} = V_{IN} + 4.3$ V, $T_A = 25^{\circ}\text{C}$, $I_{SW} = 1$ A | – | 0.25 | 0.4 | Ω |
| BOOT Undervoltage Lockout Threshold | V_{BOOTUV} | V_{BOOT} to V_{SW} increasing | 1.7 | 2.9 | 4.3 | V |
| BOOT Undervoltage Lockout Hysteresis | $V_{BOOTUVHYS}$ | V_{BOOT} to V_{SW} decreasing | – | 370 | – | mV |
| Switching Minimum Off-Time | t_{OFFmin} | $V_{CS} = 0$ V | – | 110 | 150 | ns |
| Switching Minimum On-Time | t_{ONmin} | | – | 110 | 150 | ns |
| Selected On-Time | t_{ON} | $V_{IN} = 24$ V, $V_{OUT} = 12$ V, $R_{ON} = 137$ k Ω | 800 | 1000 | 1200 | ns |
| Regulation Comparator and Error Amplifier | | | | | | |
| Load Current Sense Regulation Threshold | V_{CSREG} | V_{CS} decreasing, SW turns on | 187.5 | 200 | 210 | mV |
| Load Current Sense Bias Current | I_{CSBIAS} | $V_{CS} = 0.2$ V, EN = low | – | 0.9 | – | μA |
| Internal Linear Regulator | | | | | | |
| VCC Regulated Output | V_{CC} | $0\text{ mA} < I_{CC} < 5\text{ mA}$, $V_{IN} > 6$ V | 5.1 | 5.4 | 5.7 | V |
| VCC Current Limit* | I_{CCLIM} | $V_{IN} = 24$ V, $V_{CC} = 0$ V | 5 | 20 | – | mA |
| Enable Input | | | | | | |
| Logic High Voltage | V_{IH} | V_{EN} increasing | 1.8 | – | – | V |
| Logic Low Voltage | V_{IL} | V_{EN} decreasing | – | – | 0.4 | V |
| EN Pin Pull-down Resistance | R_{ENPD} | $V_{EN} = 5$ V | – | 100 | – | k Ω |
| Maximum PWM Dimming Off-Time | t_{PWML} | Measured while EN = low, during dimming control, and internal references are powered-on (exceeding t_{PWML} results in shutdown) | 10 | 17 | – | ms |
| Thermal Shutdown | | | | | | |
| Thermal Shutdown Threshold | T_{SD} | | – | 165 | – | $^{\circ}\text{C}$ |
| Thermal Shutdown Hysteresis | T_{SDHYS} | | – | 25 | – | $^{\circ}\text{C}$ |

*The internal linear regulator is not designed to drive an external load

Characteristic Performance

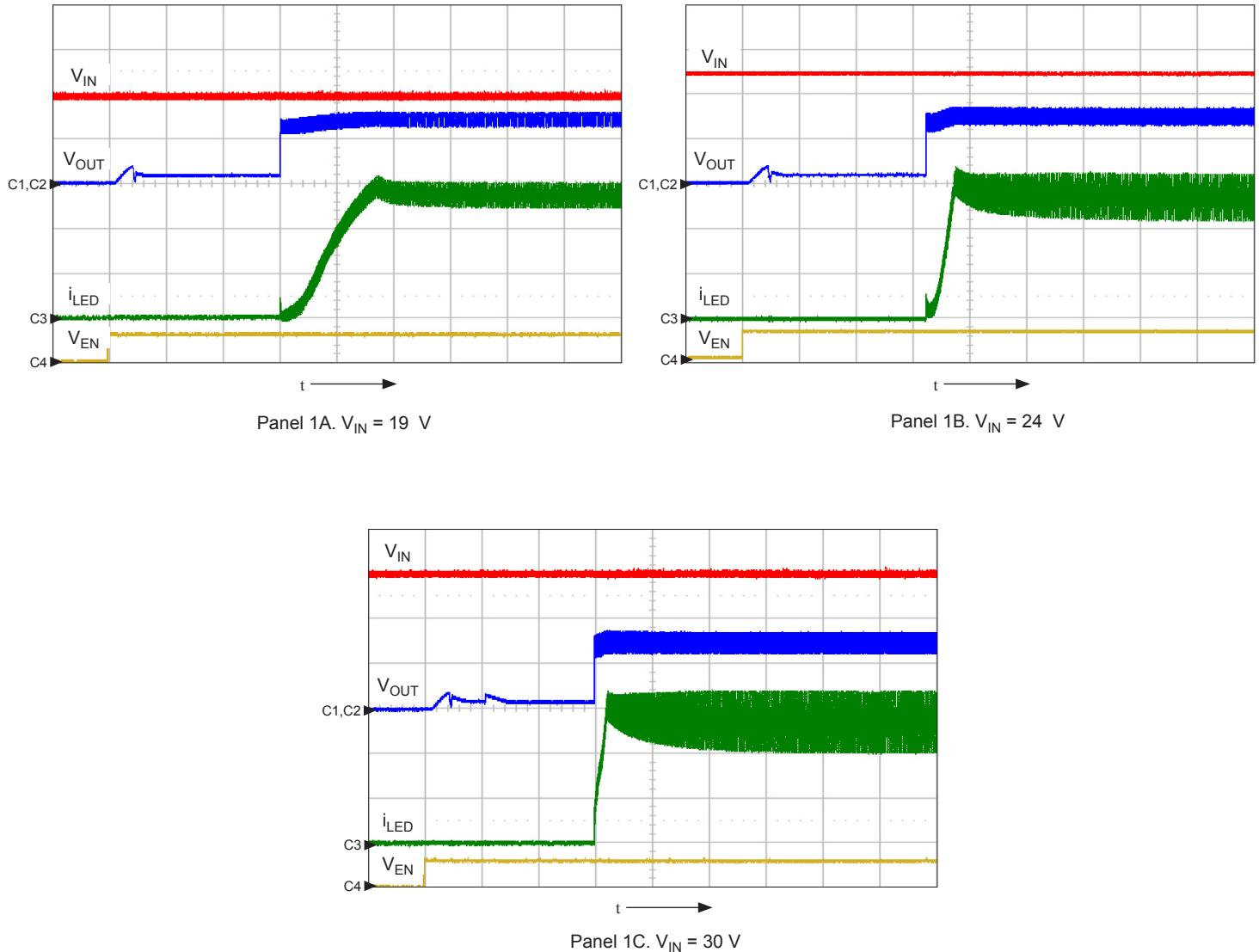
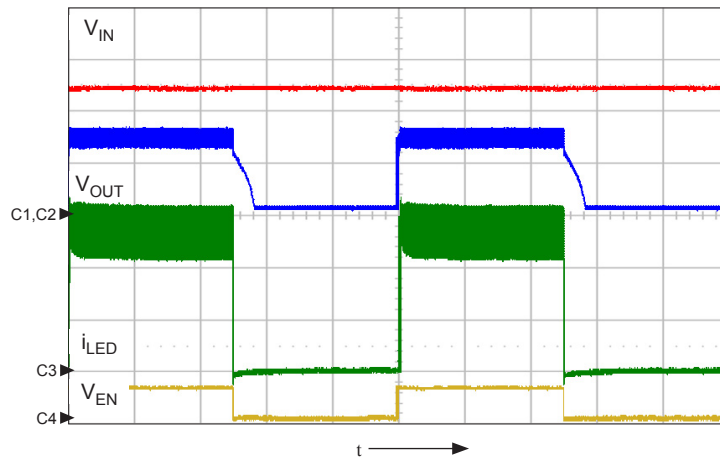
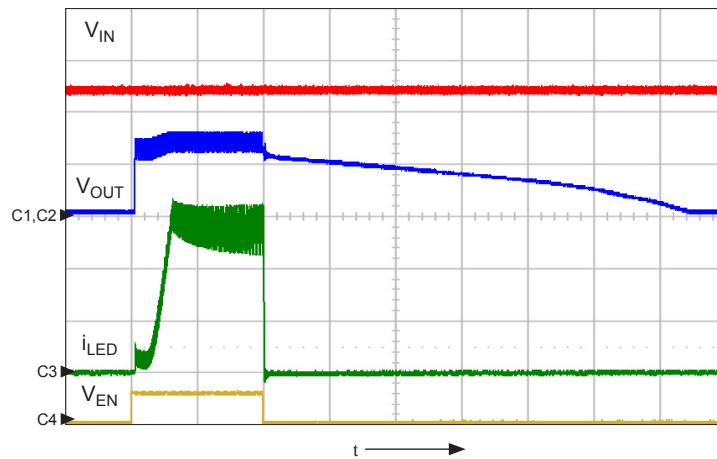


Figure 1: Startup waveforms from off-state at various input voltages; note that the rise time of the LED current depends on input/output voltages, inductor value, and switching frequency

- Operating conditions: LED voltage = 15 V, LED current = 1.3 A, $R_1 = 63.4 \text{ k}\Omega$ (frequency = 1 MHz in steady state), $V_{IN} = 19 \text{ V}$ (panel 1A), 24 V (panel 1B) and 30 V (panel 1C)
- Oscilloscope settings: CH1 (Red) = V_{IN} (10 V/div), CH2 (Blue) = V_{OUT} (10 V/div), CH3 (Green) = i_{LED} (500 mA/div), CH4 (Yellow) = Enable (5 V/div), time scale = 50 $\mu\text{s}/\text{div}$



Panel 2A: Duty cycle = 50% and time scale = 1 ms/div



Panel 2B: Duty cycle = 2% and time scale = 50 μs/div

Figure 2: PWM operation at various duty cycles; note that there is no startup delay during PWM dimming operation

- Operating conditions: at 200 Hz, $V_{IN} = 24$ V, $V_{OUT} = 15$ V, $R1 = 63.4$ k Ω , duty cycle = 50% (panel 2A) and 2% (panel 2B)
- CH1 (Red) = V_{IN} (10 V/div), CH2 (Blue) = V_{OUT} (10 V/div), CH3 (Green) = i_{LED} (500 mA/div), CH4 (Yellow) = Enable (5 V/div), time scale = 1 ms/div (panel 2A) and 50 μs/div (panel 2B)

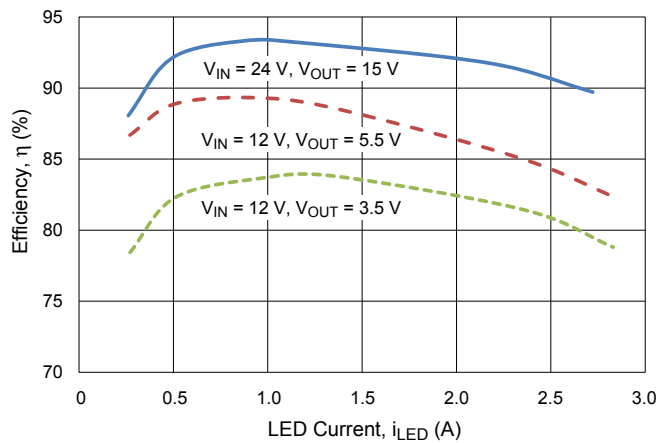


Figure 3: Efficiency versus LED Current at various LED voltages
Operating conditions: $f_{SW} = 1 \text{ MHz}$

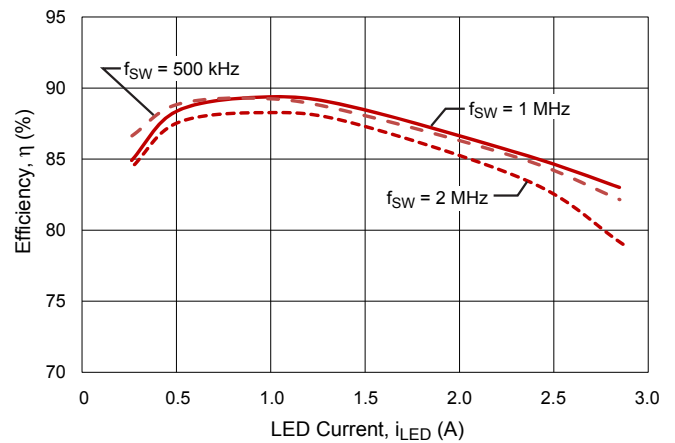


Figure 4: Efficiency versus LED Current at various switching frequencies. Operating conditions: $V_{IN} = 12 \text{ V}$, $V_{OUT} = 5.5 \text{ V}$

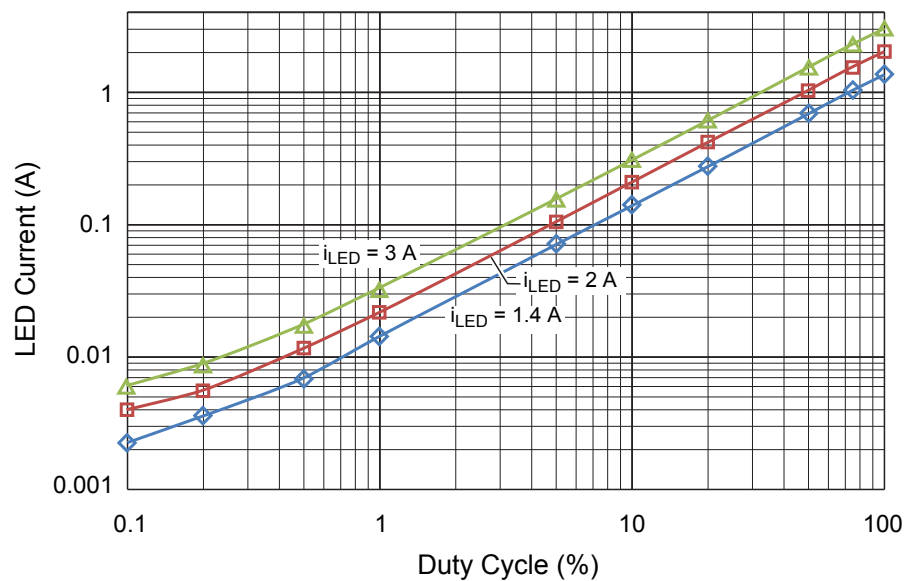


Figure 5: Average LED Current versus PWM dimming percentage
Operating conditions: $V_{IN} = 12 \text{ V}$, $V_{OUT} = 3.5 \text{ V}$, $f_{SW} = 1 \text{ MHz}$, $f_{PWM} = 200 \text{ Hz}$, $L = 10 \mu\text{H}$

Functional Description

The A6211 is a buck regulator designed for driving a high-current LED string. It utilizes average current mode control to maintain constant LED current and consistent brightness. The LED current level is easily programmable by selection of an external sense resistor, with a value determined as follows:

$$i_{LED} = V_{CSREG} / R_{SENSE}$$

where $V_{CSREG} = 0.2 \text{ V}$ typical.

Switching Frequency

The A6211 operates in fixed on-time mode during switching. The on-time (and hence switching frequency) is programmed using an external resistor connected between the VIN and TON pins, as

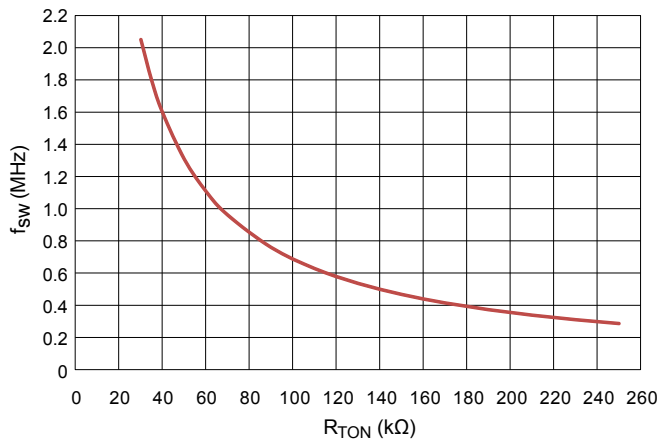
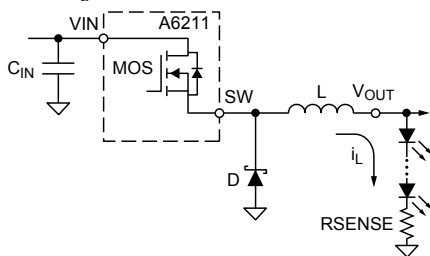


Figure 6: Switching Frequency versus R_{TON} Resistance

- During SW on-time:
 $i_{RIPPLE} = [(V_{IN} - V_{OUT}) / L] \times t_{ON} = [(V_{IN} - V_{OUT}) / L] \times T \times D$
 where $D = t_{ON} / T$.
 - During SW off-time:
 $i_{RIPPLE} = [(V_{OUT} - V_D) / L] \times t_{OFF} = [(V_{OUT} - V_D) / L] \times T \times (1 - D)$
- Therefore (simplified equation for Output Voltage):
 $V_{OUT} = V_{IN} \times D - V_D \times (1 - D)$
 If $V_D \ll V_{OUT}$, then $V_{OUT} \approx V_{IN} \times D$.
 More precisely:
 $V_{OUT} = (V_{IN} - I_{av} \times R_{DS(on)}) \times D - V_D \times (1 - D) - R_L \times I_{av}$
 where R_L is the resistance of the inductor.



given by the following equation:

$$t_{ON} = k \times (R_{ON} + R_{INT}) \times (V_{OUT} / V_{IN})$$

$$f_{SW} = 1 / [k \times (R_{ON} + R_{INT})]$$

where $k = 0.0139$, with f_{SW} in MHz, t_{ON} in μs , and R_{ON} and R_{INT} (internal resistance, 5 k Ω) in k Ω (see figure 6).

Enable and Dimming

The IC is activated when a logic high signal is applied to the EN (enable) pin. The buck converter ramps up the LED current to a target level set by RSENSE.

When the EN pin is forced from high to low, the buck converter is turned off, but the IC remains in standby mode for up to 10 ms. If EN goes high again within this period, the LED current is turned on immediately. Active dimming of the LED is achieved by sending a PWM (pulse-width modulation) signal to the EN pin. The resulting LED brightness is proportional to the duty cycle (T_{ON} / Period) of the PWM signal. A practical range for PWM dimming frequency is between 100 Hz (Period = 10 ms) and 2 kHz. At a 200 Hz PWM frequency, the dimming duty cycle can be varied from 100% down to 1% or lower.

If EN is low for more than 17 ms, the IC enters shutdown mode to reduce power consumption. The next high signal on EN will initialize a full startup sequence, which includes a startup delay of approximately 130 μs . This startup delay is not present during PWM operation.

The EN pin is high-voltage tolerant and can be directly connected to a power supply. However, if EN is higher than the V_{IN} voltage

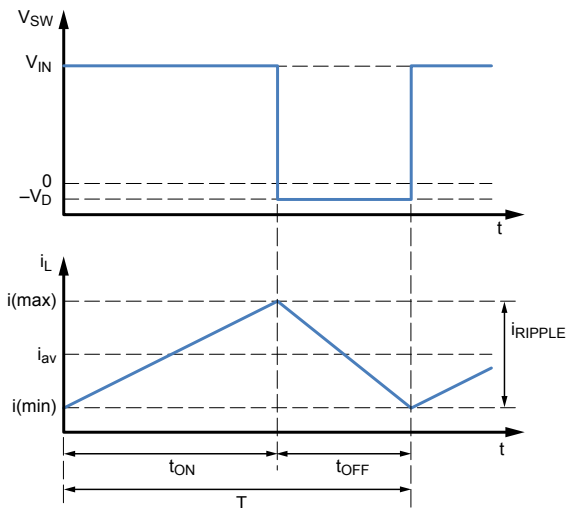


Figure 7: Simplified buck controller equations, and reference circuit and waveforms

at any time, a series resistor (1 kΩ) is required to limit the current flowing into the EN pin. This series resistor is not necessary if EN is driven from a logic input.

PWM Dimming Ratio

The brightness of the LED string can be reduced by adjusting the PWM duty cycle at the EN pin as follows:

$$\text{Dimming ratio} = \text{PWM on-time} / \text{PWM period}$$

For example, by selecting a PWM period of 5 ms (200 Hz PWM frequency) and a PWM on-time of 50 μs, a dimming ratio of 1% can be achieved.

In an actual application, the minimum dimming ratio is determined by various system parameters, including: V_{IN} , V_{OUT} , inductance, LED current, switching frequency, and PWM frequency. As a general guideline, the minimum PWM on-time should be kept at 50 μs or longer. A shorter PWM on-time is acceptable under more favorable operating conditions.

Output Voltage and Duty Cycle

Figure 7 provides simplified equations for approximating output voltage. Essentially, the output voltage of a buck converter is approximately given as:

$$V_{OUT} = V_{IN} \times D - V_{DI} \times (1 - D) \approx V_{IN} \times D, \text{ if } V_{DI} \ll V_{IN}$$

$$D = t_{ON} / (t_{ON} + t_{OFF})$$

where D is the duty cycle, and V_{DI} is the forward drop of the Schottky diode D1 (typically under 0.5 V).

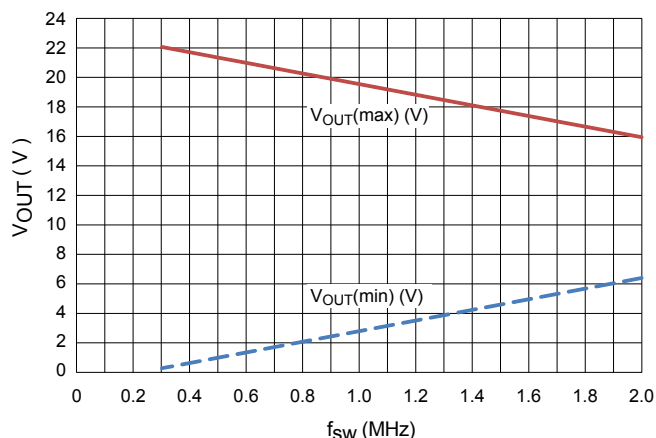


Figure 8: Minimum and Maximum Output Voltage versus Switching Frequency ($V_{IN} = 24$ V, $i_{LED} = 2$ A, minimum t_{ON} and $t_{OFF} = 150$ ns)

Minimum and Maximum Output Voltages

For a given input voltage, the maximum output voltage depends on the switching frequency and minimum t_{OFF} . For example, if $t_{OFF(min)} = 150$ ns and $f_{SW} = 1$ MHz, then the maximum duty cycle is 85%. So for a 24 V input, the maximum output is 20.3 V. This means up to 6 LEDs can be operated in series, assuming $V_f = 3.3$ V or less for each LED.

The minimum output voltage depends on minimum t_{ON} and switching frequency. For example, if the minimum $t_{ON} = 150$ ns and $f_{SW} = 1$ MHz, then the minimum duty cycle is 15%. That means with $V_{IN} = 24$ V, the minimum $V_{OUT} = 3.2$ V (one LED).

To a lesser degree, the output voltage is also affected by other factors such as LED current, on-resistance of the high-side switch, DCR of the inductor, and forward drop of the low-side diode. The more precise equation is shown in figure 7.

As a general rule, switching at lower frequencies allows a wider range of V_{OUT} , and hence more flexible LED configurations. This is shown in figure 8.

Figure 8 shows how the minimum and maximum output voltages vary with LED current (assuming $R_{DS(on)} = 0.4$ Ω, inductor DCR = 0.1 Ω, and diode $V_f = 0.6$ V).

If the required output voltage is lower than that permitted by the minimum t_{ON} , the controller will automatically extend the t_{OFF} , in order to maintain the correct duty cycle. This means that the switching frequency will drop lower when necessary, while the LED current is kept in regulation at all times.

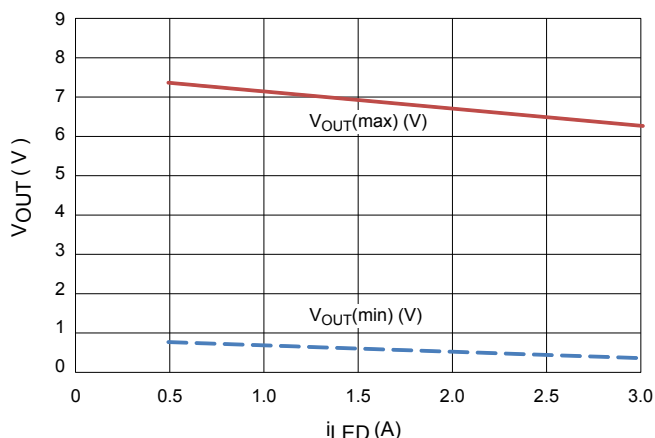


Figure 9: Minimum and Maximum Output Voltage versus i_{LED} current ($V_{IN} = 9$ V, $f_{SW} = 1$ MHz, minimum t_{ON} and $t_{OFF} = 150$ ns)

Thermal Budgeting

The A6211 is capable of supplying a 3 A current through its high-side switch. However, depending on the duty cycle, the conduction loss in the high-side switch may cause the package to overheat. Therefore care must be taken to ensure the total power loss of package is within budget. For example, if the maximum temperature rise allowed is $\Delta T = 50$ K at the device case surface, then the maximum power dissipation of the IC is 1.4 W. Assuming the maximum $R_{DS(on)} = 0.4 \Omega$ and a duty cycle of 85%, then the maximum LED current is limited to 2 A approximately. At a lower duty cycle, the LED current can be higher.

Fault Handling

The A6211 is designed to handle the following faults:

- Pin-to-ground short
- Pin-to-neighboring pin short
- Pin open
- External component open or short
- Output short to GND

The waveform in figure 10 illustrates how the A6211 responds in the case in which the current sense resistor or the CS pin is shorted to GND. Note that the SW pin overcurrent protection is tripped at around 3.75 A, and the part shuts down immediately. The part then goes through startup retry after approximately 380 μ s of cool-down period.

As another example, the waveform in figure 11 shows the fault case where external Schottky diode D1 is missing or open. As

LED current builds up, a larger-than-normal negative voltage is developed at the SW node during off-time. This voltage trips the missing Schottky detection function of the IC. The IC then shuts down immediately, and waits for a cool-down period before retry.

Component Selections

The inductor is often the most critical component in a buck converter. Follow the procedure below to derive the correct parameters for the inductor:

1. Determine the saturation current of the inductor. This can be done by simply adding 20% to the average LED current:

$$i_{SAT} \geq i_{LED} \times 1.2.$$

2. Determine the ripple current amplitude (peak-to-peak value). As a general rule, ripple current should be kept between 10% and 30% of the average LED current:

$$0.1 < i_{RIPPLE(pk-pk)} / i_{LED} < 0.3.$$

3. Calculate the inductance based on the following equations:

$$L = (V_{IN} - V_{OUT}) \times D \times T / i_{RIPPLE}, \text{ and}$$

$$D = (V_{OUT} + V_{D1}) / (V_{IN} + V_{D1}),$$

where

D is the duty cycle,

T is the period $1/f_{SW}$, and

V_{D1} is the forward voltage drop of the Schottky diode D1 (see figure 7).

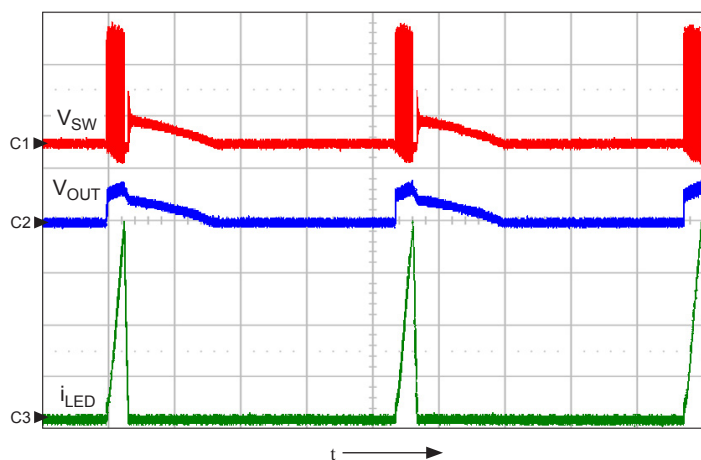


Figure 10: A6211 overcurrent protection tripped in the case of a fault caused by the sense resistor pin shorted to ground; shows switch node, V_{SW} (ch1, 10 V/div.), output voltage, V_{OUT} (ch2, 10 V/div.), LED current, i_{LED} (ch3, 1 A/div.), $t = 100 \mu$ s/div.

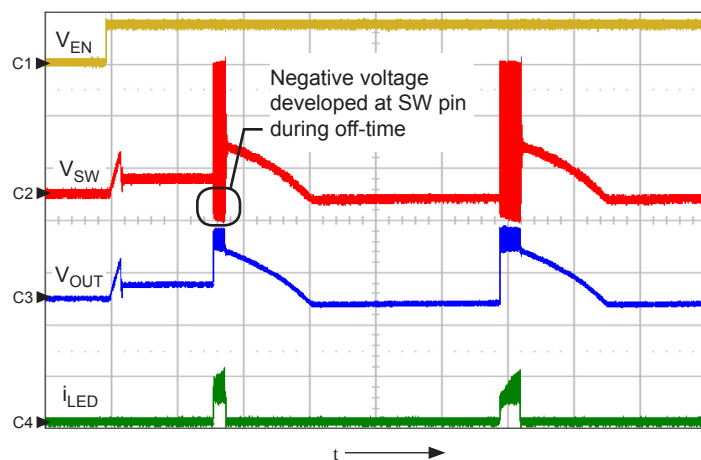


Figure 11: Startup waveform with a missing Schottky diode; shows Enable, V_{EN} (ch1, 5 V/div.), switch node, V_{SW} (ch2, 5 V/div.), output voltage, V_{OUT} (ch3, 5 V/div.), LED current, i_{LED} (ch4, 500 mA/div.), $t = 100 \mu$ s/div.

Inductor Selection Chart

The chart in figure 12 summarizes the relationship between LED current, switching frequency, and inductor value. Based on this chart: Assuming LED current = 2 A and $f_{SW}=1$ MHz, then the minimum inductance required is $L = 10 \mu\text{H}$ in order to keep the ripple current at 30% or lower. (Note: $V_{OUT} = V_{IN} / 2$ is the worst case for ripple current). If the switching frequency is lower, then either a larger inductance must be used, or the ripple current requirement has to be relaxed.

Additional Notes on Ripple Current

- For stability, pick the inductor and switching frequency to ensure the lowest inductor ripple current percentage is at least 10% during worst case (at the lowest V_{IN}).
- There is no hard limit on the highest ripple current percentage allowed. A 60% ripple current is still acceptable, as long as both the inductor and LEDs can handle the peak current (average current $\times 1.3$ in this case). However, care must be taken to ensure the valley of the inductor ripple current never drops to zero at the highest input voltage (which implies a 200% ripple current).
- In general, allowing a higher ripple current percentage enables lower-inductance inductors to be used, which results in smaller size and lower cost. The only down-side is the core loss of the inductor increases with larger ripple currents. But this is typically a small factor.
- If lower ripple current is required for the LED string, one solution is to add a small capacitor (such as $2.2 \mu\text{F}$) across the LED

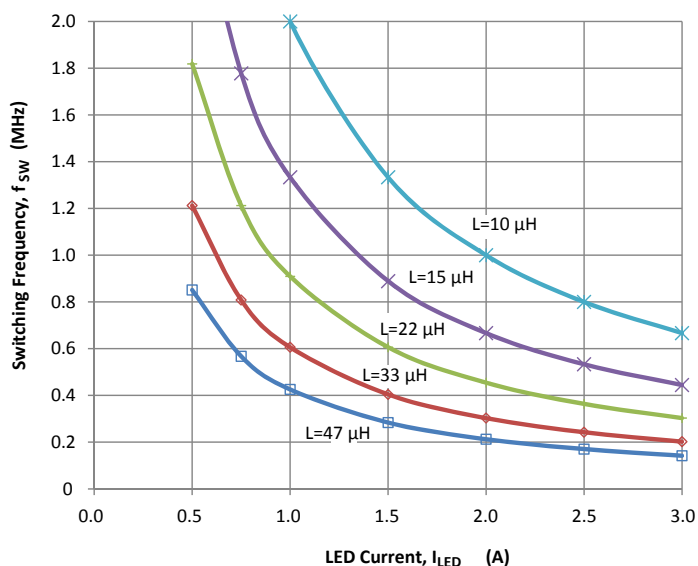
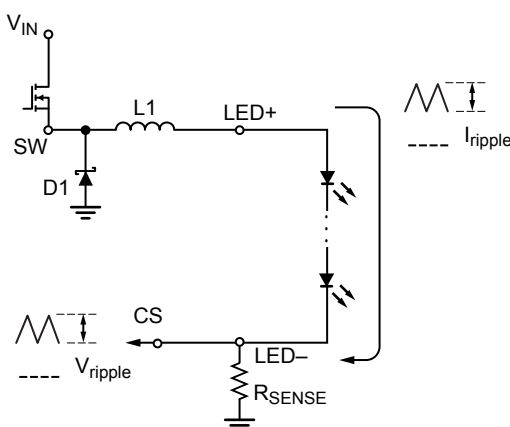
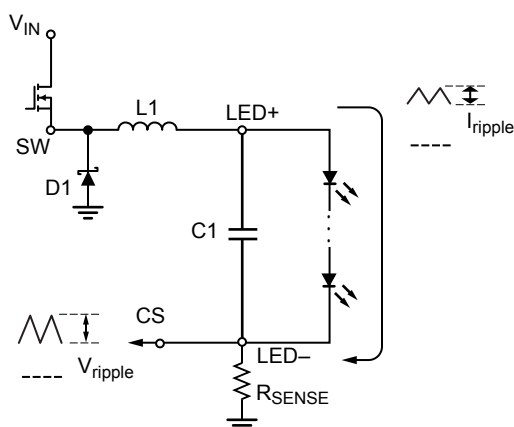


Figure 12: Inductance selection based on I_{LED} and f_{SW} ; $V_{IN} = 24 \text{ V}$, $V_{OUT} = 12 \text{ V}$, ripple current = 30%



Without output capacitor:
Ripple current through LED string is proportional to ripple voltage at CS pin.



With a small capacitor across LED string:
Ripple current through LED string is reduced, while ripple voltage at CS pin remains high.

Figure 13: Ripple current and voltage, with and without shunt capacitor

string from LED+ to LED-. In this case, the inductor ripple current remains high while the LED ripple current is greatly reduced.

Output Filter Capacitor

The A6211 is designed to operate without an output filter capacitor, in order to save cost. Adding a large output capacitor is not recommended.

In some applications, it may be required to add a small filter capacitor (up to several μF) across the LED string (between LED+ and LED-) to reduce output ripple voltage and current. It is important to note that:

- The effectiveness of this filter capacitor depends on many factors, such as: switching frequency, inductors used, PCB layout, LED voltage and current, and so forth.

- The addition of this filter capacitor introduces a longer delay in LED current during PWM dimming operation. Therefore the maximum PWM dimming ratio is reduced.

- The filter capacitor should NOT be connected between LED+ and GND. Doing so may create instability because the control loop must detect a certain amount of ripple current at the CS pin for regulation.

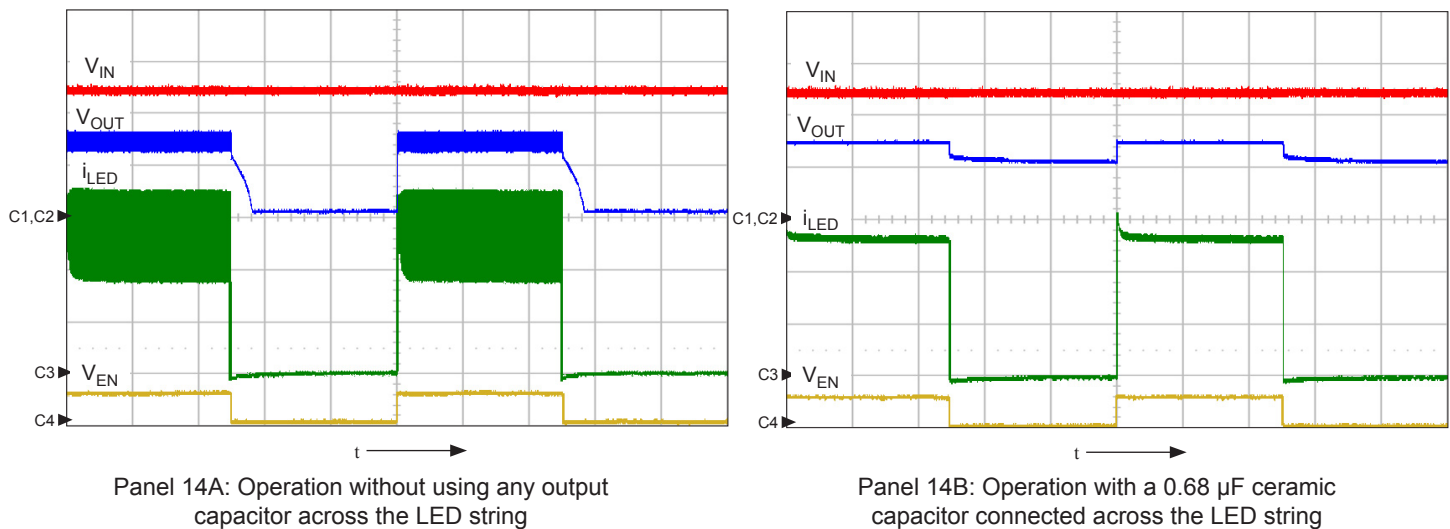


Figure 14. Waveforms showing the effects of adding a small filter capacitor across the LED string

- Operating conditions: at 200 Hz, $V_{IN} = 24\text{ V}$, $V_{OUT} = 15\text{ V}$, $f_{SW} = 500\text{ kHz}$, $L = 10\text{ }\mu\text{H}$, duty cycle = 50%
- CH1 (Red) = V_{IN} (10 V/div), CH2 (Blue) = V_{OUT} (10 V/div), CH3 (Green) = i_{LED} (500 mA/div), CH4 (Yellow) = Enable (5 V/div), time scale = 1 ms/div

Application Circuit

The application circuit in figure 15 shows a design for driving a 15 V LED string at 1.3 A (set by R_{SENSE}). The switching frequency is 500 kHz, as set by R1. A 0.68 μ F ceramic capacitor is added across the LED string to reduce the ripple current through the LEDs (as shown in figure 14B).

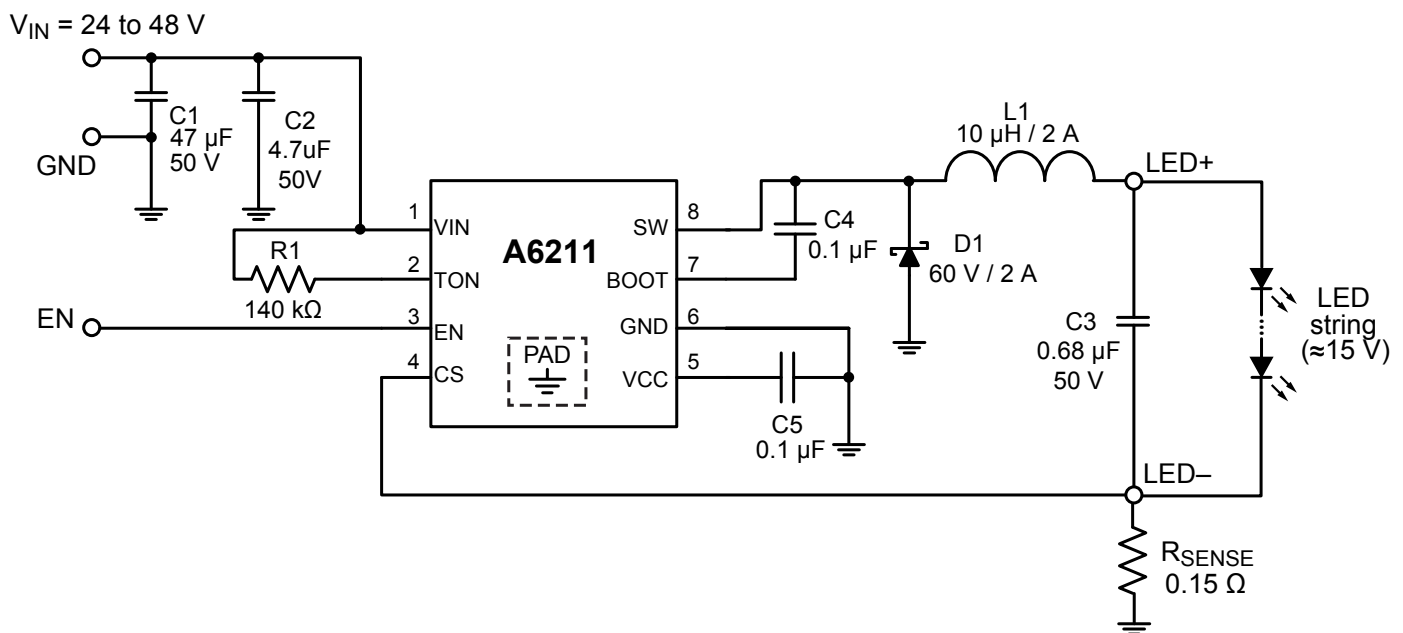


Figure 15: Application circuit diagram

| Suggested Components | | |
|----------------------|----------------------|------------------|
| Symbol | Part Number | Manufacturer |
| C1 | EMZA500ADA470MF80G | United Chemi-Con |
| C2 | UMK316BJ475KL-T | Taiyo Yuden |
| C3 | CGA5L2X5R1H684K160AA | TDK |
| L1 | NR8040T100M | Taiyo Yuden |
| D1 | B250A-13-F | Diodes, Inc. |
| R_{SENSE} | RL1632R-R150-F | Susumu |

Component Placement and PCB Layout Guidelines

PCB layout is critical in designing any switching regulator. A good layout reduces emitted noise from the switching device, and ensures better thermal performance and higher efficiency. The following guidelines help to obtain a high quality PCB layout. Figure 16 shows an example for components placement. Figure 17 shows the three critical current loops that should be minimized and connected by relatively wide traces.

1) When the upper FET (integrated inside the A6211) is on, current flows from the input supply/capacitors, through the upper FET, into the load via the output inductor, and back to ground as shown in loop 1. This loop should have relatively wide traces. Ideally this connection is made on both the top (component) layer and via the ground plane.

2) When the upper FET is off, free-wheeling current flows from ground through the asynchronous diode D1, into the load via the output inductor, and back to ground as shown in loop 2. This loop should also be minimized and have relatively wide traces. Ideally this connection is made on both the top (component) layer and via the ground plane.

3) The highest di/dt occurs at the instant the upper FET turns on and the asynchronous diode D1 undergoes reverse recovery as

shown in loop 3. The ceramic input capacitors C2 must deliver this high instantaneous current. C1 (electrolytic capacitor) should not be too far off C2. Therefore, the loop from the ceramic input capacitor through the upper FET and asynchronous diode to ground should be minimized. Ideally this connection is made on both the top (component) layer and via the ground plane.

4) The voltage on the SW node (pin 8) transitions from 0 V to V_{IN} very quickly and may cause noise issues. It is best to place the asynchronous diode and output inductor close to the A6211 to minimize the size of the SW polygon.

Keep sensitive analog signals (CS, and R1 of switching frequency setting) away from the SW polygon.

6) For accurate current sensing, the LED current sense resistor R_{SENSE} should be placed close to the IC.

7) Place the boot strap capacitor C4 near the BOOT node (pin 7) and keep the routing to this capacitor short.

8) When routing the input and output capacitors (C1, C2, and C3 if used), use multiple vias to the ground plane and place the vias as close as possible to the A6211 pads.

9) To minimize PCB losses and improve system efficiency, the input (V_{IN}) and output (V_{OUT}) traces should be wide and duplicated on multiple layers, if possible.

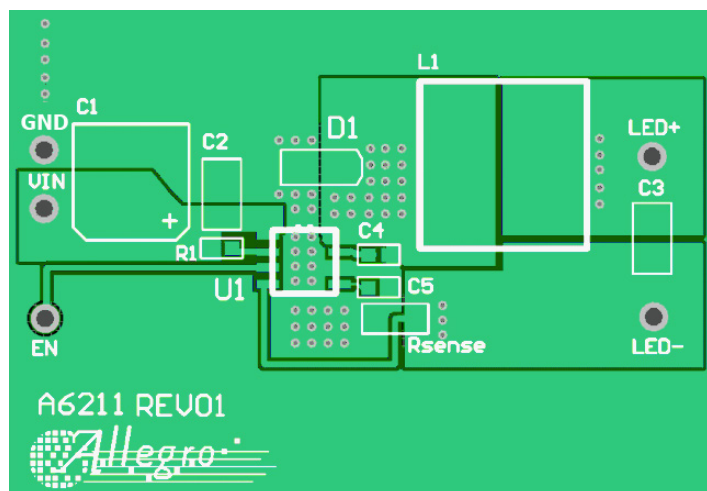


Figure 16: Example layout for the A6211 evaluation board

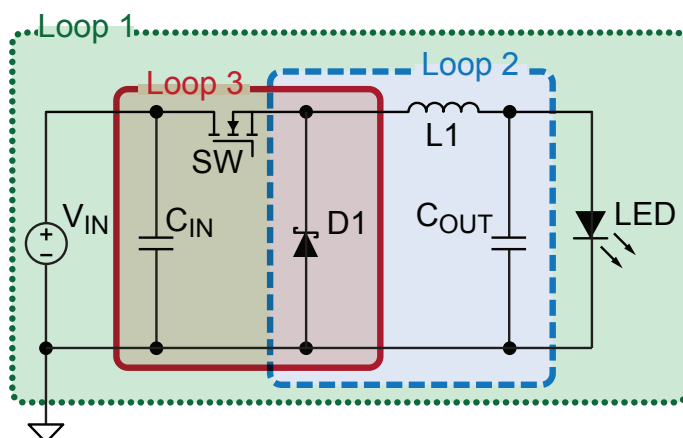


Figure 17: Three different current loops in a buck converter

10) Connection to the LED array should be kept short. Excessively long wires can cause ringing or oscillation. When the LED array is separated from the converter board and an output capacitor is used, the capacitor should be placed on the converter board to reduce the effect of stray inductance from long wires.

Thermal Dissipation

The amount of heat that can pass from the silicon of the A6211 to the surrounding ambient environment depends on the thermal resistance of the structures connected to the A6211. The thermal resistance, $R_{\theta JA}$, is a measure of the temperature rise created by power dissipation and is usually measured in degrees Celsius per watt ($^{\circ}\text{C}/\text{W}$).

The temperature rise, ΔT , is calculated from the power dissipated, P_D , and the thermal resistance, $R_{\theta JA}$, as:

$$\Delta T = P_D \times R_{\theta JA}$$

A thermal resistance from silicon to ambient, $R_{\theta JA}$, of approximately $35^{\circ}\text{C}/\text{W}$ can be achieved by mounting the A6211 on a standard FR4 double-sided printed circuit board (PCB) with a copper area of a few square inches on each side of the board under the A6211. Additional improvements in the range of 20% may be achieved by optimizing the PCB design.

Optimizing Thermal Layout

The features of the printed circuit board, including heat conduction and adjacent thermal sources such as other components, have a very significant effect on the thermal performance of the device. To optimize thermal performance, the following should be taken into account:

- The device exposed thermal pad should be connected to as much copper area as is available.
- Copper thickness should be as high as possible (for example, 2 oz. or greater for higher power applications).
- The greater the quantity of thermal vias, the better the dissipation. If the expense of vias is a concern, studies have shown that concentrating the vias directly under the device in a tight pattern, as shown in figure 18, has the greatest effect.
- Additional exposed copper area on the opposite side of the board should be connected by means of the thermal vias. The copper should cover as much area as possible.
- Other thermal sources should be placed as remote from the device as possible
- Place as many vias as possible to the ground plane around the anode of the asynchronous diode.

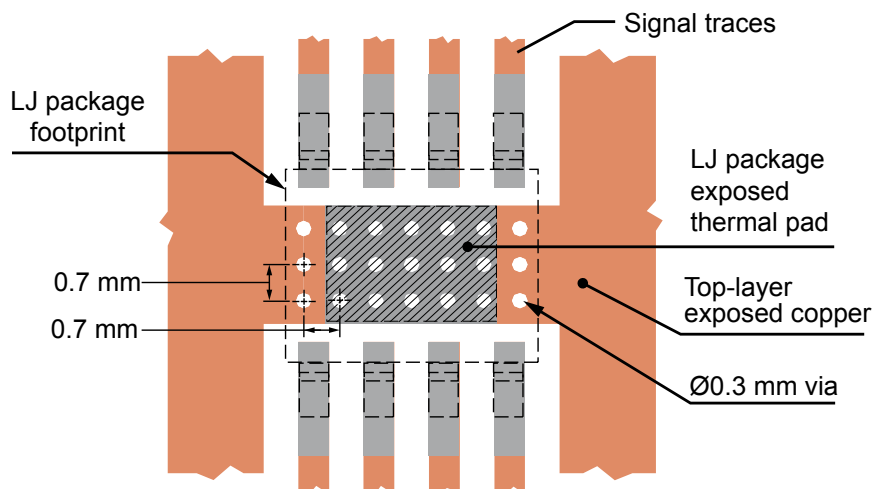
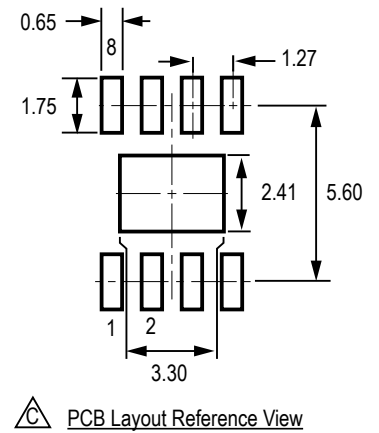
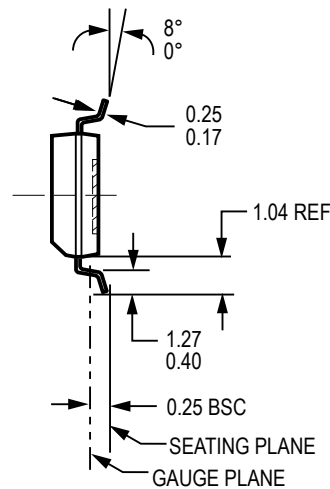
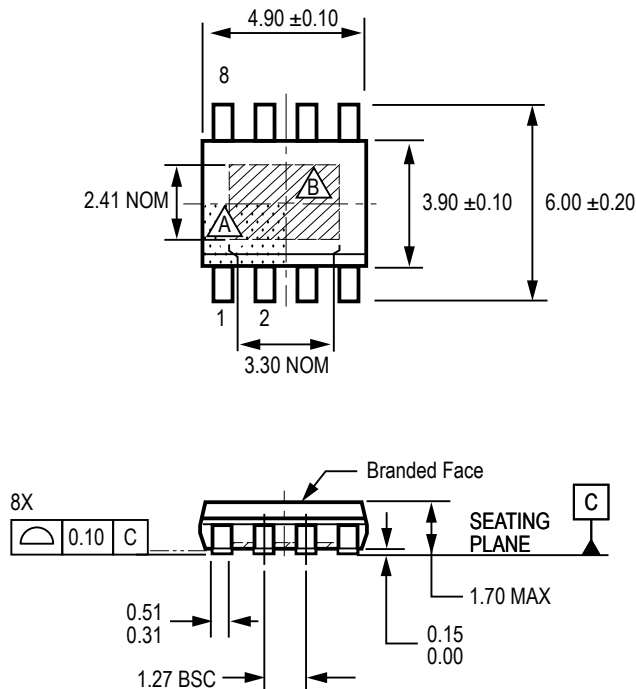


Figure 18: Suggested PCB layout for thermal optimization (maximum available bottom-layer copper recommended)

Package LJ, 8-Pin Narrow SOIC with Exposed Thermal Pad



For Reference Only; not for tooling use (reference MS-012BA)

Dimensions in millimeters

Dimensions exclusive of mold flash, gate burrs, and dambar protrusions

Exact case and lead configuration at supplier discretion within limits shown

- Terminal #1 mark area
- Exposed thermal pad (bottom surface); dimensions may vary with device
- Reference land pattern layout (reference IPC7351 SOIC127P600X175-9AM); all pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)

Revision History

| Revision | Revision Date | Description of Revision |
|----------|------------------|---|
| 1 | October 21, 2013 | Update applications information |
| 2 | March 27, 2014 | Revised VCC Spec and Suggested Components Table |

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